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### Systematic study of the spin stiffness dependence on Phosphorus alloying in (Ga,Mn)As ferromagnetic semiconductor

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We study the dependence of the spin stiffness constant on the phosphorus concentration in the ferromagnetic 13 semiconductor (Ga,Mn)(As,P) with the aim of determining whether alloying with phosphorus is detrimental, 14 neutral or advantageous to increase the spin stiffness. Time resolved magneto-optical experiments are carried 15 out in thin epilayers. Laser pulses excite two perpendicular standing spin wave modes which are exchange 16 related. We show that the first mode is spatially uniform across the layer corresponding to a  $k \approx 0$  wavevector. 17 From the two frequencies and k-vector spacings we obtain the spin stiffness constant for different phosphorus 18 concentrations using weak surface pinning conditions. The mode assessment is checked by comparison with 19 the spin stiffness obtained from domain pattern analysis for samples with out-of-plane magnetization and with 20 ferromagnetic resonance experiments when more than one spin wave mode is observed. The spin stiffness is 21 found to exhibit little variation with phosphorus concentration in contradiction with ab-initio predictions. 22

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Building complex heterostructures, such as tunnel 55 24 magnetic junctions, from the same host material is a chal- 56 25 lenge in order to reduce detrimental interface effects be- 57 26 tween different parts of a spintronic device. In this frame- 58 27 work, diluted magnetic semiconductors (DMS) are a class 59 28 of materials able to address this challenge<sup>1</sup>. More fun- 60 29 damentally, DMS and more specifically the III-V based 61 30 (Ga,Mn)As have become in the past decade a benchmark 62 31 material in order to achieve predictable tuning of mag- 63 32 netic properties. Levers such as the temperature<sup>2</sup>, the  $_{64}$ 33 carrier concentration<sup>3,4</sup> but also the strain applied on 65 34 the magnetic laver<sup>5,6</sup> or alloying with phosphorus<sup>7,8</sup> have <sup>66</sup> 35 been used in order to change the micromagnetic proper- 67 36 ties, e.g. the Curie temperature  $T_C$ , the saturation mag- 68 37 netization  $M_s$ , and the magnetic easy axis. 69 38

Among these properties, the spin stiffness D is perhaps 71 39 the most difficult to tune, despite theoretical guidelines<sup>9</sup>. 72 40 An increase of the spin stiffness keeping constant mag-73 41 nitude of the magnetization  $M_s$  would mean larger ex-74 42 change constant A ( $A = DM_s/2$ ) and therefore larger 75 43 domain wall width and domain wall velocity, this tun-76 44 ability remaining out of reach for metals. It is expected 77 45 that alloying with phosphorus should increase the spin 46 stiffness owing to an increase of Mn-hole exchange in-47 tegral  $J_{pd}$ , the stronger hybridization of the p-d wave 79 48 functions arising mainly from the smaller lattice constant  $^{\rm 80}$ 49 of GaMnP<sup>10</sup>. The effect on  $T_C$  remains theoretically <sup>81</sup> 50 unclear. Whereas an overall increase is predicted from <sup>82</sup> 51 (Ga,Mn)As to  $(Ga,Mn)P^{10,11}$ , a decrease might occur for <sup>83</sup> 52 P concentration between zero and 25  $\%^{11}.$  Furthermore  $^{\rm 84}$ 53 it was shown experimentally, that (Ga,Mn)(As,P) suffers 85 54

a metal-to-insulator transition with increasing Phosphorus concentration with a drop of its  $T_C^{12,13}$ . A modest increase of D between y = 0 and y > 6 % can be inferred from results on the exchange constant A obtained for (Ga,Mn)(As,P) samples with out-of-plane easy axis using domain pattern analysis<sup>14,15</sup>. However recent results using an optical technique suggest a decrease of Dwith P alloying but with only one (Ga,Mn)(As,P) sample studied<sup>16</sup>. Unfortunately domain pattern analysis cannot be used to determine the spin stiffness for inplane magnetized samples. To assess this value at low P concentration and in-plane easy axis, techniques based on excitation of exchange related perpendicular standing spin waves (PSSW) should instead be used. The spin stiffness constant can be extracted from the frequency spacing of excited modes. One technique is the standard ferromagnetic resonance  $(FMR)^{4,17}$ , another is the time-resolved magneto-optical Kerr effect experiment (TRMOKE)<sup>6,16,18,19</sup> recently pointed out as an optical analog of FMR for  $DMS^{19}$ . However, the condition for PSSW detection is not the same for the two techniques. Some modes undetectable by FMR are observed by TRMOKE.

Here, we report on the determination of the spin stiffness constant by TRMOKE for samples with several P and Mn concentrations. In order to assess the mode k-vector we use the results previously obtained from domain pattern analysis for out-of-plane magnetized samples<sup>15</sup>. We obtain the variation of D with phosphorus concentration up to 9 %.

Samples used for this study are epilayers of

 $(Ga_{1-x},Mn_x)(As_{1-y},P_y)$  grown on a (001) GaAs sub-86 strate and annealed 1 hour at 250°C. The thickness ob-87 tained from X-rays measurements is in the range 43-88 50nm. Samples from two sets with effective Mn concen-89 tration  $x_{eff}$  around 3.5 % and 5 % were studied.  $x_{eff}$ 90 was determined from the saturation magnetization  $M_s$ 91 measured by SQUID magnetometry. All samples were 92 characterized beforehand by FMR<sup>8</sup>. Typical FMR spec-93 tra are displayed in the inset of Fig. 1, where only one 94 PSSW mode is observed, as for most samples. This al-95 lows the determination of the magnetic anisotropy con-96 stants but precludes any estimation of the spin stiffness 97 constant. TRMOKE experiments are carried out on in-98 plane magnetized samples with zero external magnetic 99 field after a 60 mT initial preparation step. For out-100 of-plane samples an in-plane field is applied to pull the 101 magnetization into the layer plane. The laser source is 102 a Ti:Sa laser with pulse width  $\approx 130$  fs at wavelength 103  $\lambda$ =703 nm. The sample is glued on the cold finger of 104 a liquid He flow cryostat. To limit thermal effects, ex-105 periments are performed at low pump and probe fluence 106  $(F_{pump}=1.1 \ \mu J \ cm^{-2}, F_{probe}=0.4 \ \mu J \ cm^{-2})$ , with a circularly or linearly pump beam, and a probe beam lin-107 108 early polarized along the magnetization direction. At 109 low temperature a pump induced stationary increase of 110 temperature of 0.5 K is estimated. The magnetization<sub>140</sub> 111 dynamics is monitored through the Kerr rotation of the 112 polarization detected by a balanced optical bridge. 113

A typical dynamical signal is shown in Fig. 1. After 114 excitation by the pump beam at t=0, which generates a 115 transient change of the anisotropy constants and there-116 fore of the effective magnetic field, the magnetization  $is_{141}$ 117 launched into precession and relaxes toward its equilib-142 118 rium position in a few ns. The dynamical signal exhibits  $_{143}$ 119 damped oscillations with two frequencies, representing $_{144}$ 120 optically generated spin wave modes (in some samples<sup>144</sup> 121 only one frequency is detected). For most of the samples,  $\frac{145}{146}$ 122 there is no difference between linearly and circularly po-123 larized pump, except for two samples without P where 124 the second spin-wave frequency was only observed in the 125 helicity dependent signal. The TRMOKE signal is fitted 126 by the relation: 127

$$S(t) = \sum_{i} A_{i} e^{\alpha_{i} 2\pi f_{i} t} \sin(2\pi f_{i} t + \phi_{i}), \qquad (1)^{147}$$

where  $f_i$  is the frequency,  $\phi_i$  the phase,  $A_i$  the amplitude 128 and  $\alpha_i$  the effective (inhomogeneous) damping of the i-129 th excited mode. The signal in Fig. 1 is obtained in a 130 y=3.4 % sample at 12 K. Parameters from the fit are 131  $f_1=1.11\pm0.02$  GHz,  $f_2=4.03\pm0.05$  GHz ,  $\alpha_{1,2}{=}0.08$  and the amplitude ratio between the two modes is 0.3 .  $_{153}$ 132 133 To extract D from the observed frequencies, the mag-154 135 netization dynamics is modeled in a standard way, start-155 136 ing from the Landau-Lifshitz-Gilbert equation with the156 137 exchange field and without damping<sup>6,18</sup>. For in-plane<sub>157</sub> 138 easy-axis, the equations for small precession angle of the158 139

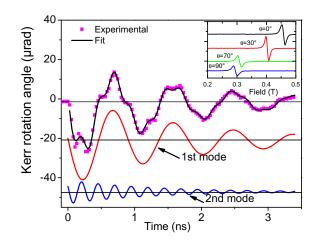


Figure 1. Typical dynamical signal obtained in TRMOKE experiments. The top curve displays the experimental signal (squares) and the associated fit (solid line) for (Ga,Mn)(As,P) with  $x_{eff} = 3.6\%$  and y = 3.4% at T=12 K. The two curves below represent the oscillatory components of the experimental signal obtained from the fit of the signal, shifted for clarity. Inset: FMR spectra at T=4 K for different angles of an out-of-plane field ( $\theta$  with respect to the [001] direction).

magnetization vector read:

$$\dot{\delta\theta} = \gamma \left[ -F_{\phi\phi} \delta\phi / M_s + D \frac{\partial^2 \delta\phi}{\partial z^2} \right]$$
$$\dot{\delta\phi} = \gamma \left[ F_{\theta\theta} \delta\theta / M_s - D \frac{\partial^2 \delta\theta}{\partial z^2} \right], \tag{2}$$

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where the z-axis (|| [001]) is perpendicular to the layer plane, and  $\theta$  and  $\phi$  are the polar and the azimuthal angles, respectively.  $F_{ij} = \frac{\partial^2 F}{\partial i \partial j} |_{\phi=\phi_0}$  are the second derivatives of the magnetic energy with respect to the spherical coordinates using FMR convention<sup>21</sup> for the anisotropy constants  $K_i$ :

$$F_{\theta\theta} = -2K_{2\perp} + K_{4\parallel} (3 + \cos 4\phi_0) /2 \qquad (3)$$
  
+2K\_{2\parallel} (1 - \sin 2\phi\_0) + \mu\_0 M\_s^2  
$$F_{\phi\phi} = 2 \left( K_{4\parallel} \cos 4\phi_0 - K_{2\parallel} \cos 2\phi_0 \right) , \qquad (4)$$

with  $\phi_0$  the equilibrium angle with respect to [100] given by  $\sin 2\phi_0 = -K_{2\parallel}/K_{4\parallel}$  if  $|K_{2\parallel}/K_{4\parallel}| < 1$  and  $\phi_0 = \pi/4$ otherwise. For an out-of-plane easy axis and an in-plane applied magnetic field the above equations are modified to include the field. Calculations of the time dependent part gives the magnon dispersion relation:

$$f(k) = \frac{\gamma}{2\pi} \sqrt{F_{\theta\theta} F_{\phi\phi}/M_s^2 \pm (F_{\theta\theta} + F_{\phi\phi})Dk^2/M_s + D^2k^4},$$
(5)

where  $\gamma$  is the gyromagnetic ratio. The plus sign refers to a bulk mode (cos kz, sin kz) and the minus one to a surface mode (cosh kz, sinh kz). Note that by setting D = 0, one recovers the Smit-Beljers formula used for FMR<sup>22</sup>. The dispersion curve for a sample with y = 4.3% at T=12 K and H=0 is displayed in Fig. 2(a). The k = 0 <sup>159</sup> frequency represents the spatially uniform mode and is <sup>160</sup> related only to the anisotropy constants, while the cur-<sup>161</sup> vature of the bulk mode dispersion curve depends on D.

<sup>162</sup> The spatial dependence of  $\delta\theta$  and  $\delta\phi$  is calculated by <sup>163</sup>finding the allowed confined surface-bulk hybridized spin <sup>164</sup> wave wavevectors for a sample thickness *L*. Following <sup>165</sup> Refs.[6,18], Rado-Weertman symmetric general bound-<sup>166</sup> ary conditions for an in-plane magnetization are used<sup>23</sup>:

$$\frac{\partial \delta \phi}{\partial z}|_{\pm L/2} = 0 \quad \frac{\partial \delta \theta}{\partial z}|_{\pm L/2} = \mp \frac{2K_s}{DM_s} \delta \theta \quad , \qquad (6)$$

where  $F_s = K_s \cos^2 \theta$  is the surface anisotropy energy 167 acting as a pinning term hindering the surface spin pre-168 cession. The natural freedom condition  $(K_s = 0)$  gives a 169 k-quantification in  $n\pi/L$ , where even (odd) n correspond 170 to even (odd) spin wave modes. Given the experimental 171 precession frequencies, the spin stiffness and the mode 172 profiles are obtained through an iterative adjustment of 173 D and  $K_s$  (Fig. 2(a)). D determines the frequency spac-174 ing between the two modes, while the pinning constant 175  $K_s$  shifts their frequencies. 176

In order to run this model, a preliminary step is to 177 check the spatial profile of the lowest energy mode. To 178 that end, a wet etching procedure was carried out on a 179 y = 4.3 % sample in order to obtain a staircase pat-180 tern (Fig.2(c)). Successive oxidation and oxide removal 181 sequences lead to a thickness difference of 5 nm be-182 tween each step. The experimental results for this sam-183 ple (Fig.2(c)) show that the first mode frequency does 184 not change with decreasing thickness while the second 185 one varies with the thickness as expected from Eqs. (5, 186 6). This shows firstly that the sample magnetic proper-187 ties have a good in-depth and lateral uniformity and, 188 secondly, that we are observing two exchange related 189 PSSWs, where the first mode is a quasi-uniform mode as 190 found from the mode profile calculation (Fig. 2(a) inset). 191 Indeed we find a very small surface anisotropy constant 192  $K_s = -1.3 \ \mu \text{J m}^{-2}$ , which divided by the layer thickness 193 gives an equivalent bulk anisotropy constant 10 times 194 smaller than the smallest bulk one (inset of Fig. 2(b)). 195

To compare FMR and optical experiments, we plot the 196 frequencies obtained from TRMOKE and the k = 0 fre-197 quency calculated from the FMR anisotropy coefficients 198 as a function of temperature. The result displayed in 199 Fig.2(b) shows an excellent agreement between these two 200 experiments for the first mode frequency. Such a com-201 parison was shown for Nickel<sup>20</sup> and for (Ga,Mn)As at one 202 temperature only<sup>18</sup> but, to our knowledge, it is the first 203 time that such a good agreement on a large temperature 204 range is demonstrated for DMS. 205

Because two PSSWs are generated, one can obtain  $D_{214}$ 206 from the frequency spacing. However the correct value<sub>215</sub> 207 of D depends on the identification of the mode k-number<sub>216</sub> 208 (and thus symmetry) for the second excited spin wave.217 209 In a TRMOKE experiment, one is not able to discrim-218 210 inate between an odd or even mode. To determine the219 211 k-number, we compared the D value obtained from stripe<sub>220</sub> 212 domain analysis<sup>15</sup> for a y = 8.8% sample (perpendicular<sub>221</sub> 213

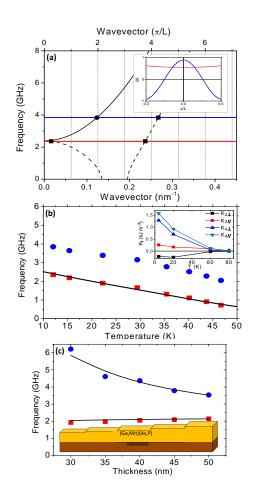


Figure 2. (a) Magnon dispersion relation showing the bulk modes (solid black line) and the surface modes (dashed black line) for a sample with y = 4.3 %, and L=50 nm. Horizontal lines represent the experimental frequencies (T=12 K). Squares (circles) represent the wavevectors of the bulk (surface) components of the spin waves found from the boundary conditions (Eq. 6). Inset: Mode profile (out-of-plane component  $\delta\theta$ ) across the layer thickness for the first and second excited modes. (b) Frequencies of spin wave modes from TRMOKE (symbols) as a function of temperature, compared with the k = 0 frequency (solid line) calculated from FMR anisotropy constants (inset). (c) Layer thickness dependence of the frequencies of the two spin wave modes observed in TRMOKE experiments for a piece of the sample y=4.3 % (T=12 K). The solid lines are the frequencies calculated from Eq. (5, 6) using  $D = 3.4 \text{ T nm}^2$ , and the anisotropy constants from FMR (inset of (b)). A sketch of the staircase-like sample after etching is shown below the curves.

easy axis),  $D = 11.8 \text{ T} \text{ nm}^2$ , with the D values obtained from TRMOKE (under in-plane field) with the assumption of an even mode,  $D = 5.4 \text{ T} \text{ nm}^2$ , or an odd mode,  $D = 21.6 \text{ T} \text{ nm}^2$ . Results from these two experiments are in better agreement with the assumption of an even second mode. The larger D from domain pattern might arise from the assumption of Bloch domain walls whereas they are actually twisted Bloch-Néel walls<sup>24</sup>. Moreover,

assuming a second even mode, we find that the values ob-267 222 tained from TRMOKE and FMR are in good agreement<sub>268</sub> 223 for this sample, which shows two modes with both tech-269 224 niques (Fig. 3). This points to a good homogeneity  $of_{270}$ 225 the sample since TRMOKE is a local probe (a few  $\mu m^2$ )<sub>271</sub> 226 whereas FMR probes the whole layer. Three GaMnAs<sub>272</sub> 227 samples (without phosphorus) have been studied. The  $D_{273}$ 228 values obtained for two of them from TRMOKE (Fig. 3),274 229 and for the third one (on a GaInAs buffer, with per-275 230 pendicular easy  $axis^{14}$ ) from domain pattern are all very<sub>276</sub> 231 close: 4.75, 4.8, and 5.1 T nm<sup>2</sup>, respectively, which again<sub>277</sub> 232 is in favor of an even second PSSW mode in TRMOKE.278 233 Let us note that the spin stiffness values for GaMnAs<sub>279</sub> 234 reported in the literature are quite dispersed, some be- $_{280}$ 235 ing comparable to  $ours^{17,18}$ , others, especially for thicker<sub>281</sub> 236 but likely inhomogeneous samples, being at least 3 times<sub>282</sub> 237 larger<sup>4,18</sup>, or 4 times larger by TRMOKE but under the<sub>283</sub> 238 assumption of a second odd mode<sup>16</sup>, which would give  $a_{284}$ 239 value close to ours assuming an even second mode. 240 205

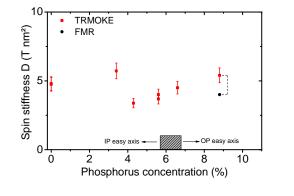


Figure 3. Dependence of the spin stiffness on the phosphorus<sup>298</sup>
concentration. Squares: from TRMOKE, circles: from FMR.<sup>299</sup>
The shaded zone indicates the frontier between samples with<sup>300</sup>
in-plane (IP) and out-of-plane (OP) easy magnetization axis.<sup>301</sup>
Data obtained from the same sample by different techniques<sup>302</sup>
are linked by a dashed line.

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TRMOKE results From we obtain Dfor<sup>306</sup> 248 (Ga,Mn)(As,P) samples with y up to  $\approx 9$  % (Fig. 3). It<sup>307</sup>... 249 is worth noticing that for two samples with the same 250 phosphorus concentration (5.6 %) but different effective<sub>310</sub> 251 Mn concentrations (3.5 % and 5 %) we obtain the same<sup>311</sup> 252 spin stiffness. Indeed, by considering the spin stiffness<sup>312</sup> 253  $D = 2A/M_s$  and not only A one takes into account the<sup>313</sup> 254  $D = 2A/M_s$  and not only A one takes into account the effect of the effective Mn concentration, which ranges<sub>315</sub> 255 here from 3.5 % to 5.2 %. As can be seen in Fig. 3,  $D_{316}$ 256 hardly varies with the Phosphorus concentration, *i.e.*<sup>317</sup> 257 with the lattice cell volume, which decreases with y. In<sup>318</sup> 258 simple models<sup>1</sup> D is expected to vary as  $p^{1/3}J_{pd}^2$ , where<sup>319</sup><sub>320</sub> 259 p is the carrier concentration. Our results can mean<sub>321</sub> 260 that  $J_{pd}$  does not increase with y. The increase of  $J_{pd^{322}}$ 261 was predicted considering relaxed layers<sup>10</sup>. However,<sup>323</sup> 262 for pseudomorphic (Ga,Mn)(As,P) layers the lattice cell<sup>324</sup> 263 volume decrease is 40 % smaller, which may diminish $^{325}_{326}$ 264 the expected variation of  $J_{pd}$ . Alternatively a small<sup>320</sup><sub>327</sub> 265 increase of  $J_{pd}$  could be counterbalanced by a decrease<sub>328</sub> 266

of the carrier concentration as suggested in Ref. [13].

As a conclusion, we have carried out time-resolved magneto-optical experiment for (Ga,Mn)(As,P) samples. Together with previous results obtained for out-of-plane easy axis samples these results allow a determination of the spin stiffness constant for phosphorus concentration ranging continuously from zero up to 9 %. The spin stiffness is found to vary hardly with the phosphorus concentration. Incorporation of phosphorus is therefore neither detrimental nor advantageous to increase the spin stiffness.

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